



PIC18F87J11 Family Silicon Errata and Data Sheet Clarification

The PIC18F87J11 family devices that you have received conform functionally to the current Device Data Sheet (DS39778D), except for the anomalies described in this document.

The silicon issues discussed in the following pages are for silicon revisions with the Device and Revision IDs listed in Table 1. The silicon issues are summarized in Table 2.

The errata described in this document will be addressed in future revisions of the PIC18F87J11 family silicon.

Note: This document summarizes all silicon errata issues from all revisions of silicon, previous as well as current. Only the issues indicated in the last column of Table 2 apply to the current silicon revision (A6).

Data Sheet clarifications and corrections start on page 5, following the discussion of silicon issues.

The silicon revision level can be identified using the current version of MPLAB® IDE and Microchip's programmers, debuggers and emulation tools, which are available at the Microchip corporate web site (www.microchip.com).

For example, to identify the silicon revision level using MPLAB IDE in conjunction with MPLAB ICD 2 or PICKit™ 3:

1. Using the appropriate interface, connect the device to the MPLAB ICD 2 programmer/debugger or PICKit™ 3.
2. From the main menu in MPLAB IDE, select Configure>Select Device, and then select the target part number in the dialog box.
3. Select the MPLAB hardware tool (Debugger>Select Tool).
4. Perform a "Connect" operation to the device (Debugger>Connect). Depending on the development tool used, the part number *and* Device Revision ID value appear in the **Output** window.

Note: If you are unable to extract the silicon revision level, please contact your local Microchip sales office for assistance.

The DEVREV values for the various PIC18F87J11 family silicon revisions are shown in Table 1.

TABLE 1: SILICON DEVREV VALUES

| Part Number | Device ID ⁽¹⁾ | Revision ID for Silicon Revision ⁽²⁾ | | | | | |
|-------------|--------------------------|---|----|----|----|----|-----|
| | | A1 | A2 | A4 | A5 | A6 | B0 |
| PIC18F66J11 | 444h | 1h | 2h | 4h | 5h | 6h | 10h |
| PIC18F66J16 | 446h | | | | | | |
| PIC18F67J11 | 448h | | | | | | |
| PIC18F86J11 | 44Eh | | | | | | |
| PIC18F86J16 | 450h | | | | | | |
| PIC18F87J11 | 452h | | | | | | |

Note 1: The Device IDs (DEVID and DEVREV) are located at the last two implemented addresses of configuration memory space. They are shown in hexadecimal in the format "DEVID DEVREV".

2: Refer to the "PIC18F6XJXX/8XJXX Flash Microcontroller Programming Specification" (DS39644) for detailed information on Device and Revision IDs for your specific device.

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TABLE 2: SILICON ISSUE SUMMARY

| Module | Feature | Item Num | Issue Summary | Affected Revisions ⁽¹⁾ | | | | | |
|--------------------------|-----------------------------------|----------|---|-----------------------------------|----|----|----|----|----|
| | | | | A1 | A2 | A4 | A5 | A6 | B0 |
| MSSPx | I ² C™ Slave Reception | 1. | When configured for I ² C slave reception, the MSSPx module may not receive the correct data if the SSPxBUF register is not read within a window after an SSPxIF interrupt occurs. | X | X | X | X | X | X |
| Oscillator Configuration | PLL | 2. | When Phase Lock Loop (PLL) is enabled, if the PLL input frequency is higher than 8 MHz, there may be problems accessing the RAM. | X | X | | | | |
| Voltage Regulator | VDDCORE | 3. | If VDDCORE drops below approximately 2.45V while the on-chip core voltage regulator is enabled and operating in Voltage Tracking mode, the REGSLP bit (WDTCON <7>) will be automatically cleared. | X | | | | | |
| SRAM | Read/Write | 4. | Any read or write access to SRAM will increase the current consumption of the device – varying with how often the SRAM is accessed. | X | | | | | |
| Low-Voltage Detect | LVDSTAT | 5. | The LVDSTAT VDDCORE status bit is not implemented in the cited revision of silicon. | X | | | | | |
| MSSPx | I ² C™ Master mode | 6. | In Master mode, the first clock may become narrower than the configuration width if the slave performs a clock stretch and release. | X | X | X | X | X | X |

Note 1: Only those issues indicated in the last column apply to the current silicon revision.

Silicon Errata Issues

Note: This document summarizes all silicon errata issues from all revisions of silicon, previous as well as current. Only the issues indicated by the shaded column in the following tables apply to the current silicon revision (A6).

1. Module: Master Synchronous Serial Port (MSSPx)

When configured for I²C™ slave reception, the MSSPx module may not receive the correct data, in extremely rare cases. This occurs only if the Serial Receive/Transmit Buffer Register (SSPxBUF) is not read within a window after the SSPxIF interrupt (PIRx<3>) has occurred.

Work around

The issue can be resolved in either of these ways:

- Prior to the I²C slave reception, enable the clock stretching feature.

This is done by setting the SEN bit (SSPxCON2<0>).

- Each time the SSPxIF is set, read the SSPxBUF before the first rising clock edge of the next byte being received.

Affected Silicon Revisions

| A1 | A2 | A4 | A5 | A6 | B0 | | |
|----|----|----|----|----|----|--|--|
| X | X | X | X | X | X | | |

2. Module: Oscillator Configurations (PLL)

When Phase Lock Loop (PLL) is enabled, if the PLL input frequency is higher than 8 MHz, there may be problems accessing the RAM.

Work around

Limit the PLL input frequency from 4 MHz to 8 MHz. This will cause the system clock to operate from 16 MHz to 32 MHz.

If it is necessary to run the device above 32 MHz, do not enable PLL and use the EC mode.

Affected Silicon Revisions

| A1 | A2 | A4 | A5 | A6 | B0 | | |
|----|----|----|----|----|----|--|--|
| X | X | | | | | | |

3. Module: Voltage Regulator

If VDDCORE drops below approximately 2.45V while the on-chip core voltage regulator is enabled, and operating in Voltage Tracking mode, the REGSLP bit (WDTCON <7>) will be automatically cleared. The REGSLP bit cannot be set again by firmware until VDDCORE rises back above the 2.45V approximate threshold.

Additionally, the REGSLP bit retains its previous state upon all Resets except POR.

Work around

None.

Affected Silicon Revisions

| A1 | A2 | A4 | A5 | A6 | B0 | | |
|----|----|----|----|----|----|--|--|
| X | | | | | | | |

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4. Module: SRAM

Any access to SRAM, either in the form of read or write operations, will increase the current consumption of the device, depending on how often the SRAM is accessed. A small current increase is normal, but in this cited silicon revision, the difference may be significant and of particular concern for low-power applications.

For further details, see Table 3.

TABLE 3: TYPICAL CURRENT CONSUMPTION

| Case 1: | | | |
|--|-----------------------|---------------------|-------------------------|
| Voltage Regulator Enabled Temperature = 25°C SEC_RUN mode using 32 kHz Timer1 Crystal | | | |
| Condition | ID _{DD} (μA) | V _{DD} (V) | |
| No RAM access ⁽¹⁾ | 59 | 3.3 | |
| Typ RAM access ⁽²⁾ | 201 | 3.3 | |
| Extreme RAM access ⁽³⁾ | 906 | 3.3 | |
| Case 2: | | | |
| Voltage Regulator Disabled V _{DDCORE} is tied to V _{DD} Temperature = 25°C SEC_RUN mode using 32 kHz Timer1 Crystal | | | |
| Condition | ID _{DD} (μA) | V _{DD} (V) | V _{DDCORE} (V) |
| No RAM access ⁽¹⁾ | 20 | 2.5 | 2.5 |
| Typ RAM access ⁽²⁾ | 132 | 2.5 | 2.5 |
| Extreme RAM access ⁽³⁾ | 723 | 2.5 | 2.5 |

- Note 1:** Code execution patterns where no instructions access SRAM.
2: Code execution that accesses SRAM once every seven instruction cycles.
3: Code execution where every instruction cycle executes an instruction that accesses SRAM.

Work around

None.

Affected Silicon Revisions

| A1 | A2 | A4 | A5 | A6 | B0 | | |
|----|----|----|----|----|----|--|--|
| X | | | | | | | |

5. Module: Low-Voltage Detect

The LVDSTAT, V_{DDCORE} status bit (WDTCON<6>), is not implemented in this revision of silicon.

Work around

None.

Affected Silicon Revisions

| A1 | A2 | A4 | A5 | A6 | B0 | | |
|----|----|----|----|----|----|--|--|
| X | | | | | | | |

6. Module: MSSPx (I²C™ Master)

If the module is in I²C Master mode, and the slave performs clock stretching, the first clock pulse after the slave releases the SCLx line may be narrower than the configured clock width. This may result in the slave missing the first clock in the next transmission/reception.

Work around

If the module is in I²C Master mode, do not allow the slave to perform clock stretching. Alternately, the master can slow down the SCLx clock frequency to a level where the slave can detect the narrowed clock pulse.

Affected Silicon Revisions

| A1 | A2 | A4 | A5 | A6 | B0 | | |
|----|----|----|----|----|----|--|--|
| X | X | X | X | X | X | | |

Data Sheet Clarifications

The following typographic corrections and clarifications are to be noted for the latest version of the device data sheet (DS39778D):

Note: Corrections are shown in **bold**. Where possible, the original bold text formatting has been removed for clarity.

1. Module: Table 27-1: Memory Programming Requirements

On page 398, the parameter, D132, which provides the minimum and maximum voltage levels of the Self-Timed Erase or Write for VDD and VDDCORE, are included. A new parameter (D133B) is added. The TWE parameter number and conditions column are changed. The changed/ appended values are indicated in bold text in the following table:

TABLE 27-1: MEMORY PROGRAMMING REQUIREMENTS

| DC CHARACTERISTICS | | | Standard Operating Conditions (unless otherwise stated) Operating temperature $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ for industrial | | | | |
|-----------------------------|------------|--|---|-------------|------------|-----------|--|
| Param No. | Sym | Characteristic | Min | Typ† | Max | Units | Conditions |
| Program Flash Memory | | | | | | | |
| D130 | EP | Cell Endurance | 10K | — | — | E/W | -40°C to +85°C V _{MIN} = Minimum operating voltage |
| D131 | VPR | VDD for Read | V _{MIN} | — | 3.6 | V | |
| D132 | VPEW | Voltage for Self-Timed Erase or Write | | | | | |
| | | VDD | 2.35 | — | 3.6 | V | ENVREG tied to VDD |
| | | VDDCORE | 2.25 | — | 2.7 | V | ENVREG tied to Vss |
| D133A | TIW | Self-Timed Write Cycle Time | — | 2.8 | — | ms | |
| D133B | TIE | Self-Timed Page Erase Cycle Time | — | 33.0 | — | ms | |
| D134 | TRETD | Characteristic Retention | 20 | — | — | Year | Provided no other specifications are violated |
| D135 | IDDP | Supply Current during Programming | — | 3 | 14 | mA | |
| D140 | TWE | Writes per Erase Cycle | — | — | 1 | — | For each physical address |

† Data in “Typ” column is at 3.3V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

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2. Module: Table 27-2: Comparator Specifications

On page 399, the maximum Input Offset Voltage (Parameter No. D300) is changed to ± 25 mV.

The parameter numbers for TRESP and TMC2OV are changed to D303 and D304, respectively.

A new parameter, D305, for VIRV is added.

The changed/appended values are indicated in bold text in the following table:

TABLE 27-2: COMPARATOR SPECIFICATIONS

| Operating Conditions: $3.0V < V_{DD} < 3.6V$, $-40^{\circ}C < T_A < +85^{\circ}C$ (unless otherwise stated) | | | | | | | |
|--|-------------|--|-----|------------|----------------------------|----------|----------|
| Param No. | Sym | Characteristics | Min | Typ | Max | Units | Comments |
| D300 | VIOFF | Input Offset Voltage | — | ± 5.0 | ± 25 | mV | |
| D301 | VICM | Input Common Mode Voltage | 0 | — | $AV_{DD} - 1.5$ | V | |
| D302 | CMRR | Common Mode Rejection Ratio | 55 | — | — | dB | |
| D303 | TRESP | Response Time ⁽¹⁾ | — | 150 | 400 | ns | |
| D304 | TMC2OV | Comparator Mode Change to Output Valid | — | — | 10 | μs | |
| D305 | VIRV | Internal Reference Voltage | — | 1.2 | — | V | |

Note 1: Response time measured with one comparator input at $(V_{DD} - 1.5)/2$, while the other input transitions from VSS to VDD.

3. Module: Table 27-4: Internal Voltage Regulator Specifications

On page 399, the comments column for the CEFC is changed. The note which states “These parameters are characterized but not tested” is removed.

The changed content is indicated in bold text in the following table:

TABLE 27-4: INTERNAL VOLTAGE REGULATOR SPECIFICATIONS

| Operating Conditions: $-40^{\circ}C < T_A < +85^{\circ}C$ (unless otherwise stated) | | | | | | | |
|---|--------|----------------------------------|-----|-----|-----|---------|---|
| Param No. | Sym | Characteristics | Min | Typ | Max | Units | Comments |
| | VRGOUT | Regulator Output Voltage* | — | 2.5 | — | V | |
| | CEFC | External Filter Capacitor Value* | 4.7 | 10 | — | μF | Capacitor must be low series resistance (<5 Ohms) |

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4. Module: Section 27.3 “DC Characteristics: PIC18F87J11 Family (Industrial)”

On page 396, the characteristics and conditions of the Input Leakage Current are updated for the Analog (D060) and included for the Digital (D060A) I/O ports. The changed values are indicated in bold text in the following table:

| DC CHARACTERISTICS | | | Standard Operating Conditions (unless otherwise stated) Operating temperature $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ for industrial | | | |
|--------------------|----------|--|---|---------------|---------------|---|
| Param No. | Symbol | Characteristic | Min | Max | Units | Conditions |
| | V_{IL} | Input Low Voltage All I/O Ports: | | | | |
| D030 | | with TTL Buffer | V_{SS} | $0.15 V_{DD}$ | V | $V_{DD} < 3.3\text{V}$ |
| D030A | | | — | 0.8 | V | $3.3\text{V} \leq V_{DD} \leq 3.6\text{V}$ |
| D031 | | with Schmitt Trigger Buffer | V_{SS} | $0.2 V_{DD}$ | V | |
| D032 | | $\overline{\text{MCLR}}$ | V_{SS} | $0.2 V_{DD}$ | V | |
| D033 | | OSC1 | V_{SS} | $0.3 V_{DD}$ | V | HS, HSPLL modes |
| D033A | | OSC1 | V_{SS} | $0.2 V_{DD}$ | V | EC, ECPLL modes |
| D034 | | T1CKI | V_{SS} | 0.3 | V | |
| | V_{IH} | Input High Voltage I/O Ports with Non 5.5V Tolerance:⁽²⁾ | | | | |
| D040 | | with TTL Buffer | $0.25 V_{DD} + 0.8\text{V}$ | V_{DD} | V | $V_{DD} < 3.3\text{V}$ |
| D040A | | | 2.0 | V_{DD} | V | $3.3\text{V} \leq V_{DD} \leq 3.6\text{V}$ |
| D041 | | with Schmitt Trigger Buffer | $0.8 V_{DD}$ | V_{DD} | V | |
| | | I/O Ports with 5.5V Tolerance:⁽²⁾ | | | | |
| Dxxx | | with TTL Buffer | $0.25 V_{DD} + 0.8\text{V}$ | 5.5 | V | $V_{DD} < 3.3\text{V}$ |
| DxxxA | | | 2.0 | 5.5 | V | $3.3\text{V} \leq V_{DD} \leq 3.6\text{V}$ |
| Dxxx | | with Schmitt Trigger Buffer | $0.8 V_{DD}$ | 5.5 | V | |
| D042 | | $\overline{\text{MCLR}}$ | $0.8 V_{DD}$ | V_{DD} | V | |
| D043 | | OSC1 | $0.7 V_{DD}$ | V_{DD} | V | HS, HSPLL modes |
| D043A | | OSC1 | $0.8 V_{DD}$ | V_{DD} | V | EC, ECPLL modes |
| D044 | | T1CKI | 1.6 | V_{DD} | V | |
| | I_{IL} | Input Leakage Current⁽¹⁾ | | | | |
| D060 | | I/O Ports with Non 5.5V Tolerance⁽²⁾ | — | ± 1 | μA | $V_{SS} \leq V_{PIN} \leq V_{DD}$, Pin at high-impedance |
| D060A | | I/O Ports with 5.5V Tolerance⁽²⁾ | — | ± 1 | μA | $V_{SS} \leq V_{PIN} \leq 5.5\text{V}$, Pin at high-impedance |
| D061 | | $\overline{\text{MCLR}}$ | — | ± 1 | μA | $V_{SS} \leq V_{PIN} \leq V_{DD}$ |
| D063 | | OSC1 | — | ± 5 | μA | $V_{SS} \leq V_{PIN} \leq V_{DD}$ |

Note 1: Negative current is defined as current sourced by the pin.

2: Refer to Table 10-1 for the pins that have corresponding tolerance limits.

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5. Module: Example 6-2: Erasing a Flash Program Memory Row

On page 94, an instruction to enable the write process to memory for erasing the Flash programming memory row is missing in the example. The changed content is indicated in bold text in the following example:

EXAMPLE 6-2: ERASING A FLASH PROGRAM MEMORY ROW

```
MOV LW CODE_ADDR_UPPER           ; load TBLPTR with the base
MOV WF TBLPTRU                   ; address of the memory block
MOV LW CODE_ADDR_HIGH
MOV WF TBLPTRH
MOV LW CODE_ADDR_LOW
MOV WF TBLPTRL
ERASE_ROW
    BSF EECON1, WREN              ; enable write to memory
    BSF EECON1, FREE             ; enable Row Erase operation
    BCF INTCON, GIE             ; disable interrupts
Required MOV LW 55h
Sequence MOV WF EECON2           ; write 55h
MOV LW 0AAh
MOV WF EECON2                   ; write 0AAh
BSF EECON1, WR                  ; start erase (CPU stall)
BSF INTCON, GIE                 ; re-enable interrupts
```

6. Module: Section 19.3 “SPI Mode” and Section 19.4 “I²C™ Mode”

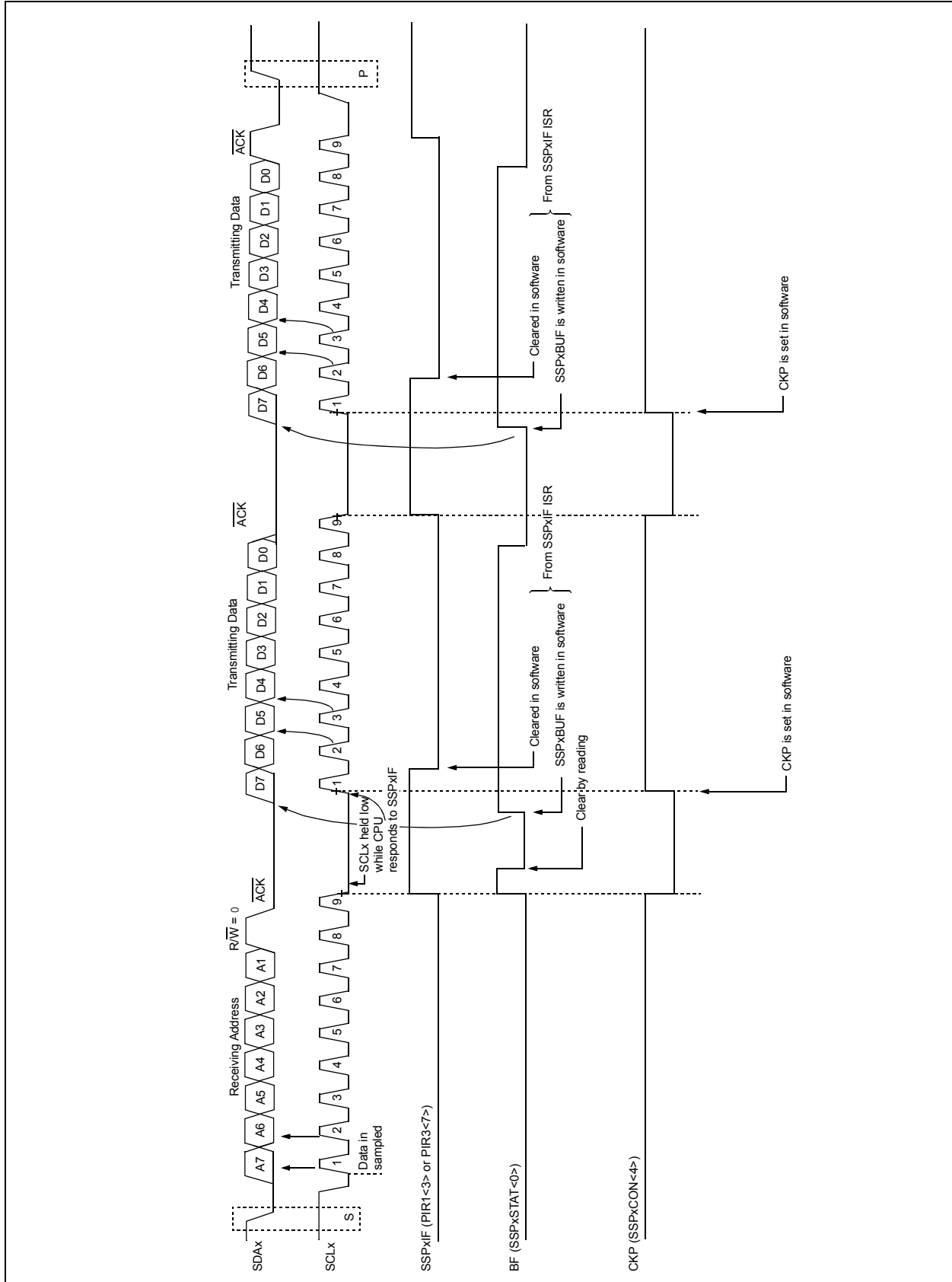
In Section 19.3 “SPI Mode” on page 223 and Section 19.4 “I²C™ Mode” on page 233, the following new note is included to describe the procedure to disable the MSSPx module:

Note: Disabling the MSSPx module by clearing the SSPEN (SSPxCON1<5>) bit may not reset the module. It is recommended to clear the SSPxSTAT, SSPxCON1 and SSPxCON2 registers and select the mode prior to setting the SSPEN bit to enable the MSSPx module.

7. Module: Figure 19-10: I²C™ Slave Mode Timing (Transmission, 7-Bit Address)

On page 244, the figure is replaced with the new timing diagram provided in Figure 19-10.

FIGURE 19-10: I²C™ SLAVE MODE TIMING (TRANSMISSION, 7-BIT ADDRESS)



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8. Module: Figure 19-24: I²C™ Master Mode Waveform (Reception, 7-Bit Address)

On page 261, the condition (R/\overline{W}) when the Acknowledge signal (ACK) is received from the slave, after transmitting the address to the slave, is changed to '1'. The changed value is indicated in bold text in Figure 19-24.

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9. Module: Table 1-3: PIC18F6XJ1X Pinout I/O Descriptions

On page 20, the pin type for the RF3, RF4 and RF5 pins are changed from I (Input) to I/O (Input/Output). The changed content is indicated in bold text in the following table.

| Pin Name | Pin Number | Pin Type | Buffer Type | Description |
|----------------------|------------|------------|-------------|---|
| | 64-TQFP | | | |
| RF1/AN6/C2OUT | 17 | | | PORTF is a bidirectional I/O port. Digital I/O. Analog input 6. Comparator 2 output. |
| RF1 | | I/O | ST | |
| AN6 | | I | Analog | |
| C2OUT | | O | — | |
| RF2/PMA5/AN7/C1OUT | 16 | | | Digital I/O. Parallel Master Port address. Analog input 7. Comparator 1 output. |
| RF2 | | I/O | ST | |
| PMA5 | | O | — | |
| AN7 | | I | Analog | |
| C1OUT | | O | — | |
| RF3/AN8/C2INB | 15 | | | Digital I/O. Analog input 8. Comparator 2 input B. |
| RF3 | | I/O | ST | |
| AN8 | | I | Analog | |
| C2INB | | I | Analog | |
| RF4/AN9/C2INA | 14 | | | Digital I/O. Analog input 8. Comparator 2 input A. |
| RF4 | | I/O | ST | |
| AN9 | | I | Analog | |
| C2INA | | I | Analog | |
| RF5/AN10/C1INB/CVREF | 13 | | | Digital I/O. Analog input 10. Comparator 1 input B. Comparator reference voltage output. |
| RF5 | | I/O | ST | |
| AN10 | | I | Analog | |
| C1INB | | I | Analog | |
| CVREF | | O | Analog | |
| RF6/AN11/C1INA | 12 | | | Digital I/O. Analog input 11. Comparator 1 input A. |
| RF6 | | I/O | ST | |
| AN11 | | I | Analog | |
| C1INA | | I | Analog | |
| RF7/SS1 | 11 | | | Digital I/O. SPI slave select input. |
| RF7 | | I/O | ST | |
| SS1 | | I | TTL | |

Legend: TTL = TTL compatible input
 ST = Schmitt Trigger input with CMOS levels
 I = Input
 P = Power
 CMOS = CMOS compatible input or output
 Analog = Analog input
 O = Output
 OD = Open-Drain (no P diode to VDD)

Note 1: Default assignment for ECCP2/P2A when Configuration bit, CCP2MX, is set.
2: Alternate assignment for ECCP2/P2A when Configuration bit, CCP2MX, is cleared.

10. Module: Memory Organization

On page 75, the note at the end of **Section 5.3.4 “Special Function Registers”** has been amended. The new information is indicated in bold text.

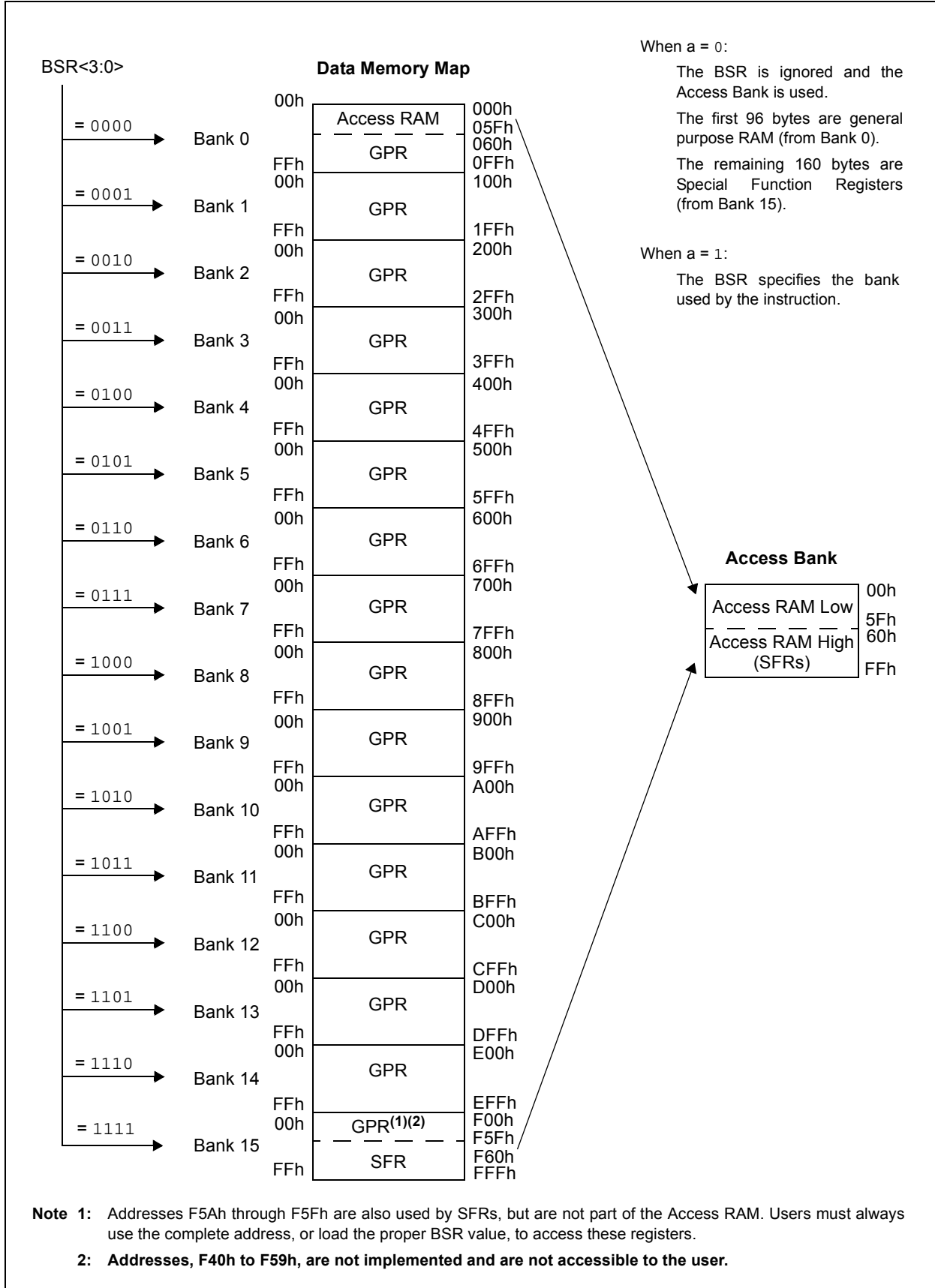
Note: Addresses, F5Ah through F5Fh, are not part of the Access Bank. These registers must always be accessed using the Bank Select Register. **Addresses, F40h to F59h, are not implemented and not accessible to the user.**

11. Module: Memory Organization

On page 73, in Figure 5-7, Note 2 has been added. The additional note is indicated in bold text in Figure 5-7.

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FIGURE 5-7: DATA MEMORY MAP FOR PIC18F87J11 FAMILY DEVICES



DOCUMENT REVISION HISTORY

Rev A Document (2/2010)

Combined existing silicon and data sheet errata documents into the new, single document format. Added the A6 silicon revision, but no issues or clarifications.

This document replaces these errata documents:

- DS80418A, "*PIC18F87J11 Family Rev. A5 Silicon Errata*"
- DS80417A, "*PIC18F87J11 Family Rev. A4 Silicon Errata*"
- DS80344A, "*PIC18F87J11 Family Rev. A2 Silicon Errata*"
- DS80305B, "*PIC18F87J11 Family Rev. A1 Silicon Errata*"
- DS80408B, "*PIC18F87J11 Family Data Sheet Errata*"

Rev B Document (7/2010)

Added silicon issue 6 (MSSPx I²C™ Master).

Added data sheet clarifications 10 and 11 (Memory Organization).

Rev C Document (8/2010)

Added silicon revision B0; includes existing silicon issues 1 (Master Synchronous Serial Port – MSSPx) and 6 (MSSPx – I²C Master).

No new data sheet clarifications added.

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NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
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